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- Current Sense Discharge Transistor to Improve Dynamic Response
- 130-μA Typical Starting Current
- 1-mA Typical Run Current
- Operation to 1 MHz
- Internal Soft Start
- On-Chip Error Amplifier With 2-MHz Gain Bandwidth Product
- On Chip VDD Clamping
- Output Drive Stages Capable of 500-mA
 Peak-Source Current, 1-A Peak-Sink Current

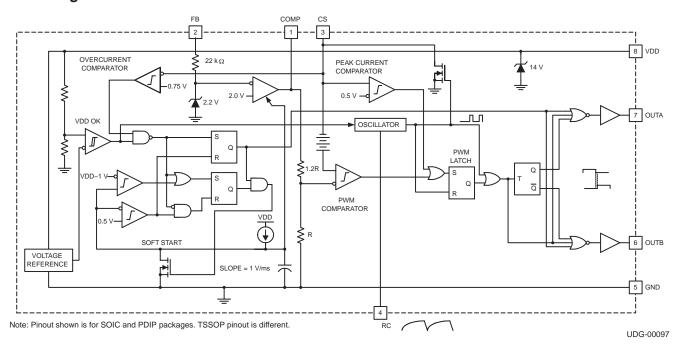
D OR N PACKAGE (TOP VIEW) VDD 8 COMP FΒ 7 **OUTA OUTB** CS П 3 6 ∏ **GND** RC 5 **PW PACKAGE** (TOP VIEW) 8 □ OUTB OUTA \square 7 ☐ GND VDD I 2 COMP [3 6 TT RC ⊐ cs FB \square 5

description

The UCC3808A is a family of BiCMOS push-pull, high-speed, low-power, pulse-width modulators. The UCC3808A contains all of the control and drive circuitry required for off-line or dc-to-dc fixed frequency current-mode switching power supplies with minimal external parts count.

The UCC3808A dual output drive stages are arranged in a push-pull configuration. Both outputs switch at half the oscillator frequency using a toggle flip-flop. The dead time between the two outputs is typically 60 ns to 200 ns depending on the values of the timing capacitor and resistors, thus limiting each output stage duty cycle to less than 50%.

block diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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description (continued)

The UCC3808A family offers a variety of package options, temperature range options, and choice of undervoltage lockout levels. The family has UVLO thresholds and hysteresis options for off-line and battery powered systems. Thresholds are shown in the table below.

The UCC3808A is an enhanced version of the UCC3808 family. The significant difference is that the A versions feature an internal discharge transistor from the CS pin to ground, which is activated each clock cycle during the oscillator dead time. The feature discharges any filter capacitance on the CS pin during each cycle and helps minimize filter capacitor values and current sense delay.

ORDERING INFORMATION

| | Packaged Devices | | | | | | | | | |
|---------------|------------------|-------------|-------------|--------------|--|--|--|--|--|--|
| $T_A = T_J$ | UVLO Option | SOIC (D)† | PDIP (N) | TSSOP (PW)† | | | | | | |
| 4000 4 0500 | 12.5 V/8.3 V | UCC2808AD-1 | UCC2808AN-1 | UCC2808APW-1 | | | | | | |
| -40°C to 85°C | 4.3 V/4.1 V | UCC2808AD-2 | UCC2808AN-2 | UCC2808APW-2 | | | | | | |
| 000 1- 7000 | 12.5 V/8.3 V | UCC3808AD-1 | UCC3808AN-1 | UCC3808APW-1 | | | | | | |
| 0°C to 70°C | 4.3 V/4.1 V | UCC3808AD-2 | UCC3808AN-2 | UCC3808APW-2 | | | | | | |

[†] D (SOIC-8) and PW (TSSOP-8) packages are available taped and reeled. Add TR suffix to device type (e.g. UCC3808ADTR-1) to order quantities of 2500 devices per reel for SOIC-8 and 2000 devices per reel for TSSOP-8.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)

| | . , |
|---|--|
| Supply voltage (IDD ≤ 10 mA) | 15 V |
| Supply current | |
| OUTA/OUTB source current (peak) | |
| OUTA/OUTB sink current (peak) | 1.0 A |
| Analog inputs (FB, CS) | -0.3 V to VDD + 0.3 V, not to exceed 6 V |
| Power dissipation at T _A = 25°C (N package) | |
| Power dissipation at T _A = 25°C (D package) | 650 mW |
| Power dissipation at T _A = 25°C (PW package) | 400 mW |
| Storage temperature, T _{stq} | –65°C to150°C |
| Junction temperature, T _J | |
| Lead temperature (soldering, 10 sec.) | |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

electrical characteristics, T_A = 0°C to 70°C for the UCC3808A-x, -40°C to 85°C for the UCC2808A-x, VDD = 10 V (see Note 6), 1- μ F capacitor from VDD to GND, R = 22 k Ω , C = 330 pF T_A = T_J , (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------------|-----------------|------|-----|------|-------|
| Oscillator Section | | | | | |
| Oscillator frequency | | 175 | 194 | 213 | kHz |
| Oscillator amplitude/VDD | See Note 1 | 0.44 | 0.5 | 0.56 | V/V |

NOTES: 1. Measured at RC. Signal amplitude tracks VDD.

6. For UCCx808A-1, set VDD above the start threshold before setting at 10 V.



[†] Currents are positive into, negative out of the specified terminal. Consult Packaging Section of the *Power Supply Control Data Book (TI Literature Number SLUD003)* for thermal limitations and considerations of packages.

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electrical characteristics, T_A = 0°C to 70°C for the UCC3808A-x, -40°C to 85°C for the UCC2808A-x, VDD = 10 V (see Note 6), 1- μ F capacitor from VDD to GND, R = 22 k Ω , C = 330 pF T_A = T_J , (unless otherwise noted)

| Error Amplifior Coction | | | | | | |
|---------------------------------------|-----------------------|---------------------------|------|------|------|-----|
| Error Amplifier Section | 00117 011 | | | | | |
| Input voltage | COMP = 2 V | | 1.95 | 2 | 2.05 | V |
| Input bias current | | | -1 | | 1 | μΑ |
| Open loop voltage gain | | | 60 | 80 | | dB |
| COMP sink current | FB = 2.2 V, | COMP = 1 V | 0.3 | 2.5 | | mA |
| COMP source current | FB = 1.3 V, | COMP = 3.5 V | -0.2 | -0.5 | | mA |
| PWM Section | | | | | | |
| Maximum duty cycle | Measured at OUT | TA or OUTB | 48 | 49 | 50 | % |
| Minimum duty cycle | COMP = 0 V | | | | 0 | % |
| Current Sense Section | | | | | | |
| Gain | See Note 2 | | 1.9 | 2.2 | 2.5 | V/V |
| Maximum input signal | COMP = 5 V | See Note 3 | 0.45 | 0.5 | 0.55 | V |
| CS to output delay | COMP = 3.5 V, | CS from 0 mV to 600 mV | | 100 | 200 | ns |
| CS source current | | | -200 | | | nA |
| CS sink current | CS = 0.5 V, | RC = 5.5 V See Note 7 | 5 | 10 | | mA |
| Over current threshold | | | 0.7 | 0.75 | 0.8 | V |
| COMP to CS offset | CS = 0 V | | 0.35 | 0.8 | 1.2 | V |
| Output Section | • | | | | | |
| OUT low level | I = 100 mA | | | 0.5 | 1 | V |
| OUT high level | I = -50 mA, | VDD – OUT | | 0.5 | 1 | V |
| Rise time | C _L = 1 nF | | | 25 | 60 | ns |
| Fall time | C _L = 1 nF | | | 25 | 60 | ns |
| Undervoltage Lockout Section | - | | | | U . | |
| | UCCx808A-1 | See Note 6 | 11.5 | 12.5 | 13.5 | V |
| Start threshold | UCCx808A-2 | | 4.1 | 4.3 | 4.5 | V |
| | UCCx808A-1 | | 7.6 | 8.3 | 9 | V |
| Minimum operating voltage after start | UCCx808A-2 | | 3.9 | 4.1 | 4.3 | V |
| | UCCx808A-1 | | 3.5 | 4.2 | 5.1 | V |
| Hysteresis | UCCx808A-2 | | 0.1 | 0.2 | 0.3 | V |
| Soft Start Section | | | 1 | | | |
| COMP rise time | FB = 1.8 V, | Rise from 0.5 V to 4 V | | 3.5 | 20 | ms |
| Overall Section | | | 1 | | | |
| Startup current | VDD < start thres | hold | | 130 | 260 | μА |
| Operating supply current | FB = 0 V, | CS = 0 V See Note 5 and 6 | | 1 | 2 | mA |
| VDD zener shunt voltage | IDD = 10 mA | See Note 4 | 13 | 14 | 15 | V |
| | | 2-2-11 212 -1 | | | . • | • |

NOTES: 2. Gain is defined by: $A = \frac{\Delta V_{COMP}}{\Delta V_{CS}}$, $0 \le V_{CS} \le 0.4 \text{ V}$.

- 3. Parameter measured at trip point of latch with FB at 0 V.
- 4. Start threshold and zener shunt threshold track one another.
- 5. Does not include current in the external oscillator network.
- 6. For UCCx808A-1, set VDD above the start threshold before setting at 10 V.
- 7. The internal current sink on the CS pin is designed to discharge an external filter capacitor. It is not intended to be a dc sink path.



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pin assignments

COMP: COMP is the output of the error amplifier and the input of the PWM comparator. The error amplifier in the UCC3808A is a true low-output impedance, 2-MHz operational amplifier. As such, the COMP pin can both source and sink current. However, the error amplifier is internally current limited, so that zero duty cycle can be externally forced by pulling COMP to GND.

The UCC3808A family features built-in full-cycle soft start. Soft start is implemented as a clamp on the maximum COMP voltage.

CS: The input to the PWM, peak current, and overcurrent comparators. The overcurrent comparator is only intended for fault sensing. Exceeding the overcurrent threshold will cause a soft start cycle. An internal MOSFET discharges the current sense filter capacitor to improve dynamic performance of the power converter.

FB: The inverting input to the error amplifier. For best stability, keep FB lead length as short as possible and FB stray capacitance as small as possible.

GND: Reference ground and power ground for all functions. Due to high currents, and high frequency operation of the UCC3808A, a low impedance circuit board ground plane is highly recommended.

OUTA and OUTB: Alternating high current output stages. Both stages are capable of driving the gate of a power MOSFET. Each stage is capable of 500-mA peak-source current, and 1-A peak-sink current.

The output stages switch at half the oscillator frequency, in a push-pull configuration. When the voltage on the RC pin is rising, one of the two outputs is high, but during fall time, both outputs are off. This *dead time* between the two outputs, along with a slower output rise time than fall time, insures that the two outputs can not be on at the same time. This dead time is typically 60 ns to 200 ns and depends upon the values of the timing capacitor and resistor.

The high-current-output drivers consist of MOSFET output devices, which switch from VDD to GND. Each output stage also provides a very low impedance to overshoot and undershoot. This means that in many cases, external-schottky-clamp diodes are not required.

RC: The oscillator programming pin. The UCC3808A's oscillator tracks VDD and GND internally, so that variations in power supply rails minimally affect frequency stability. Figure 1 shows the oscillator block diagram.

Only two components are required to program the oscillator: a resistor (tied to the VDD and RC), and a capacitor (tied to the RC and GND). The approximate oscillator frequency is determined by the simple formula:

$$f_{OSCILLATOR} = \frac{1.41}{RC}$$

where frequency is in Hz, resistance in Ohms, and capacitance in Farads. The recommended range of timing resistors is between 10 k Ω and 200 k Ω and range of timing capacitors is between 100 pF and 1000 pF. Timing resistors less than 10 k Ω should be avoided.

For best performance, keep the timing capacitor lead to GND as short as possible, the timing resistor lead from VDD as short as possible, and the leads between timing components and RC as short as possible. Separate ground and VDD traces to the external timing network are encouraged.



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pin assignments (continued)

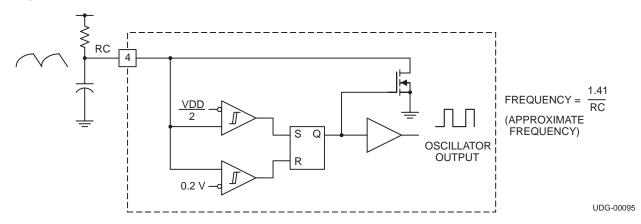


Figure 1. Block Diagram for Oscillator

NOTE A: The oscillator generates a sawtooth waveform on RC. During the RC rise time, the output stages alternate on time, but both stages are off during the RC fall time. The output stages switch a 1/2 the oscillator frequency, with ensured duty cycle of < 50% for both outputs.

VDD: The power input connection for this device. Although quiescent VDD current is very low, total supply current will be higher, depending on OUTA and OUTB current, and the programmed oscillator frequency. Total VDD current is the sum of quiescent VDD current and the average OUT current. Knowing the operating frequency and the MOSFET gate charge (Qg), average OUT current can be calculated from:

$$I_{OUT} = Q_q \times F$$
, where F is frequency

To prevent noise problems, bypass VDD to GND with a ceramic capacitor as close to the chip as possible along with an electrolytic capacitor. A 1-μF decoupling capacitor is recommended.

APPLICATION INFORMATION

A 200-kHz push-pull application circuit with a full-wave rectifier is shown in Figure 2. The output, V_O , provides 5 V at 50 W maximum and is electrically isolated from the input. Since the UCC3808A is a peak-current-mode controller the 2N2907 emitter following amplifier (buffers the CT waveform) provides slope compensation which is necessary for duty ratios greater than 50%. Capacitor decoupling is very important with a single ground IC controller, and a 1 μ F is suggested as close to the IC as possible. The controller supply is a series RC for start-up, paralleled with a bias winding on the output inductor used in steady state operation.

Isolation is provided by an optocoupler with regulation done on the secondary side using the TL431 adjustable precision shunt regulator. Small signal compensation with tight voltage regulation is achieved using this part on the secondary side. Many choices exist for the output inductor depending on cost, volume, and mechanicall strength. Several design options are iron powder, molypermalloy (MPP), or a ferrite core with an air gap as shown here. The main power transformer has a Magnetics Inc. ER28 size core made of P material for efficient operation at this frequency and temperature. The input voltage may range from 36 V dc to 72 V dc.



APPLICATION INFORMATION

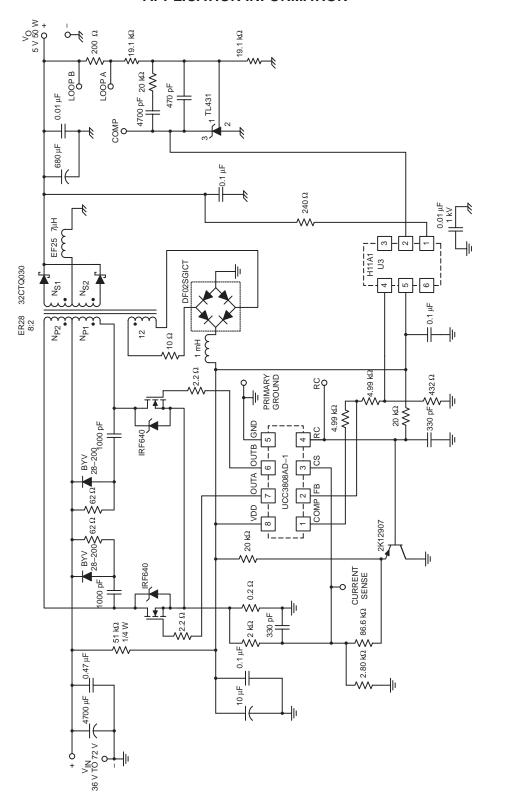
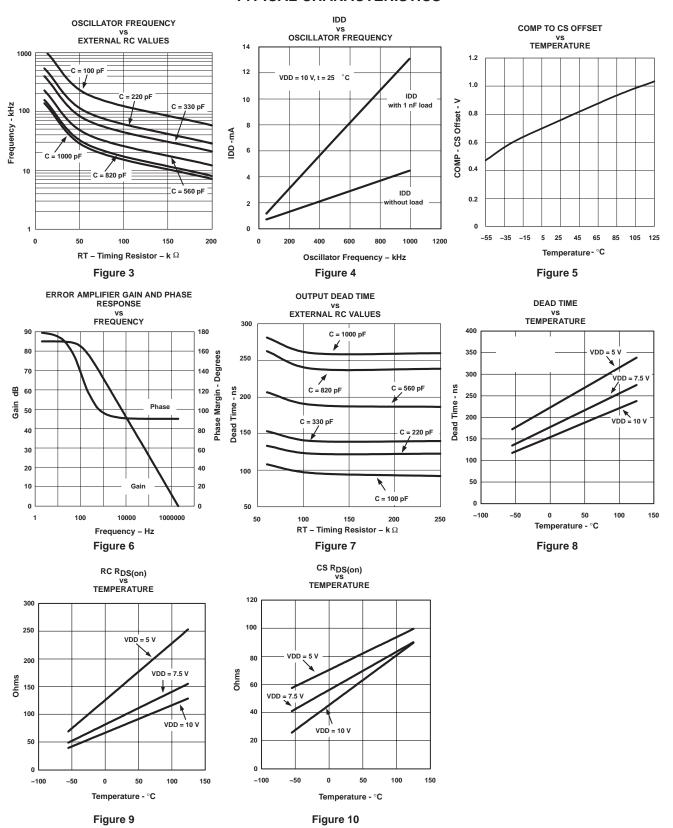


Figure 2. Typical Application Diagram: 48-V In, 5-V, 50-W Output

UDG-00096



TYPICAL CHARACTERISTICS









10-Aug-2016

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | _ | Pins | - | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|---------------------|--------------|-----------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| UCC2808AD-1 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-1 | Sample |
| UCC2808AD-1G4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-1 | Sample |
| UCC2808AD-2 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-2 | Sample |
| UCC2808AD-2G4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-2 | Samples |
| UCC2808ADTR-1 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-1 | Samples |
| UCC2808ADTR-1G4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-1 | Samples |
| UCC2808ADTR-2 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-2 | Samples |
| UCC2808ADTR-2G4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 2808A-2 | Samples |
| UCC2808AN-1 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | -40 to 85 | UCC2808A N-1 | Samples |
| UCC2808AN-2 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | -40 to 85 | UCC2808A N-2 | Samples |
| UCC2808AN-2G4 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | -40 to 85 | UCC2808A N-2 | Samples |
| UCC2808APW-1 | ACTIVE | TSSOP | PW | 8 | 150 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | 2808A1 | Samples |
| UCC2808APW-1G4 | ACTIVE | TSSOP | PW | 8 | 150 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | 2808A1 | Samples |
| UCC2808APW-2 | ACTIVE | TSSOP | PW | 8 | 150 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | 2808A2 | Samples |
| UCC2808APW-2G4 | ACTIVE | TSSOP | PW | 8 | 150 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | 2808A2 | Samples |
| UCC2808APWTR-1 | ACTIVE | TSSOP | PW | 8 | | TBD | Call TI | Call TI | -40 to 85 | 2808A1 | Samples |
| UCC2808APWTR-2 | ACTIVE | TSSOP | PW | 8 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | 2808A2 | Samples |





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| Orderable Device | Status | Package Type | _ | Pins | _ | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|---------------------|--------------|-----------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| UCC3808AD-1 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-1 | Samples |
| UCC3808AD-1G4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-1 | Samples |
| UCC3808AD-2 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-2 | Samples |
| UCC3808AD-2G4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-2 | Samples |
| UCC3808ADTR-1 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-1 | Samples |
| UCC3808ADTR-1G4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-1 | Samples |
| UCC3808ADTR-2 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-2 | Samples |
| UCC3808ADTR-2G4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 3808A-2 | Samples |
| UCC3808AN-1 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | UCC3808A N-1 | Samples |
| UCC3808AN-1G4 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | UCC3808A N-1 | Samples |
| UCC3808AN-2 | ACTIVE | PDIP | Р | 8 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | UCC3808A N-2 | Samples |
| UCC3808APW-2 | ACTIVE | TSSOP | PW | 8 | 150 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | 3808A2 | Samples |
| UCC3808APWTR-2 | ACTIVE | TSSOP | PW | 8 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | 3808A2 | Samples |
| JCC3808APWTR-2G4 | ACTIVE | TSSOP | PW | 8 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | 3808A2 | Samples |

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

10-Aug-2016

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| UCC2808ADTR-1 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| UCC2808ADTR-2 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| UCC2808APWTR-2 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| UCC3808ADTR-1 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| UCC3808ADTR-2 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| UCC3808APWTR-2 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |

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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| UCC2808ADTR-1 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| UCC2808ADTR-2 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| UCC2808APWTR-2 | TSSOP | PW | 8 | 2000 | 367.0 | 367.0 | 35.0 |
| UCC3808ADTR-1 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| UCC3808ADTR-2 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| UCC3808APWTR-2 | TSSOP | PW | 8 | 2000 | 367.0 | 367.0 | 35.0 |

IMPORTANT NOTICE

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